

Replaces DS6074-1

DRD3390V40

Rectifier Diode

DS6074-2 June 2013 (LN30616)

FEATURES		KEY PARAMETERS		
•	Double Side Cooling	V _{RRM}	4000V	
•	High Surge Capability	I _{F(AV)}	3388A	

FSM

APPLICATIONS

- Rectification
- Free-wheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{RRM} V	Conditions
DRD3390V40 DRD3390V39 DRD3390V38 DRD3390V37 DRD3390V36 DRD3390V35	4000 3900 3800 3700 3600 3500	V _{RSM} = V _{RRM} +100V

Lower voltage grades available.

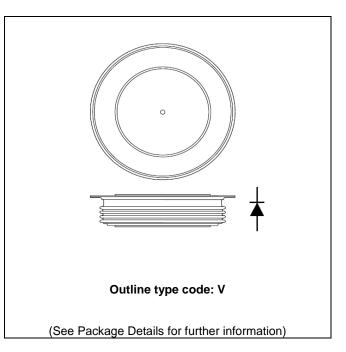
ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD3390V37 for a 3700V device

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.



62500A

Fig. 1 Package outlines

CURRENT RATINGS

 $T_{case} = 75^{\circ}C$ unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled		1	
I _{F(AV)}	Mean forward current	Half wave resistive load	4366	А
I _{F(RMS)}	RMS value	-	6858	А
I _F	Continuous (direct) on-state current	-	6561	А
Single Sid	e Cooled (Anode side)			
I _{F(AV)}	Mean forward current	Half wave resistive load	2926	А
I _{F(RMS)}	RMS value	-	4596	А
I _F	Continuous (direct) on-state current	-	4066	А

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			1
I _{F(AV)}	Mean forward current	Half wave resistive load	3388	А
I _{F(RMS)}	RMS value	-	5321	А
I _F	Continuous (direct) on-state current	-	4983	А
Single Sic	le Cooled (Anode side)	•		
I _{F(AV)}	Mean forward current	Half wave resistive load	2232	Α
I _{F(RMS)}	RMS value	-	3506	Α
I _F	Continuous (direct) on-state current	-	3015	А

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$	50.0	kA
l ² t	I ² t for fusing	$V_R = 50\% V_{RRM}$ - ¼ sine	12.5	MA ² s
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$	62.5	kA
l ² t	I ² t for fusing	V _R = 0	19.6	MA ² s

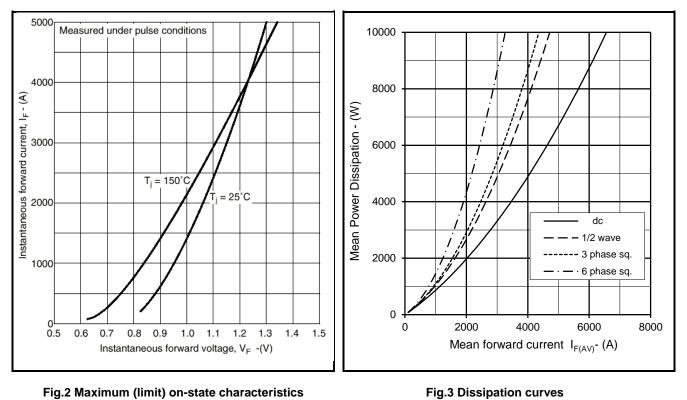
THERMAL AND MECHANICAL RATINGS

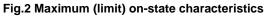
Symbol	Parameter	Test Condition	S	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.0075	°C/W
		Single side cooled	Anode DC	-	0.015	°C/W
			Cathode DC	-	0.015	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 43kN	Double side	-	0.002	°C/W
		(with mounting compound)	Single side	-	0.004	°C/W
T _{vj}	Virtual junction temperature	On-state (conducting)		-	160	°C
		Reverse (blocking)		-	150	°C
T _{stg}	Storage temperature range			-55	150	°C
Fm	Clamping force			38.0	47.0	kN

CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 3000A peak, T _{case} = 25°C	-	1.15	V
I _{RM}	Peak reverse current	At V _{DRM,} T _{case} = 150°C	-	250	mA
Qs	Total stored charge	I _F = 2000A, dI _{RR} /dt =3A/µs	-	5000	μC
Irr	Peak reverse recovery current	$T_{case} = 150^{\circ}C, V_{R} = 100V$	-	150	А
V _{TO}	Threshold voltage	At T _{vj} = 150°C	-	0.75	V
r⊤	Slope resistance	At T _{vj} = 150°C	-	0.118	mΩ

CURVES



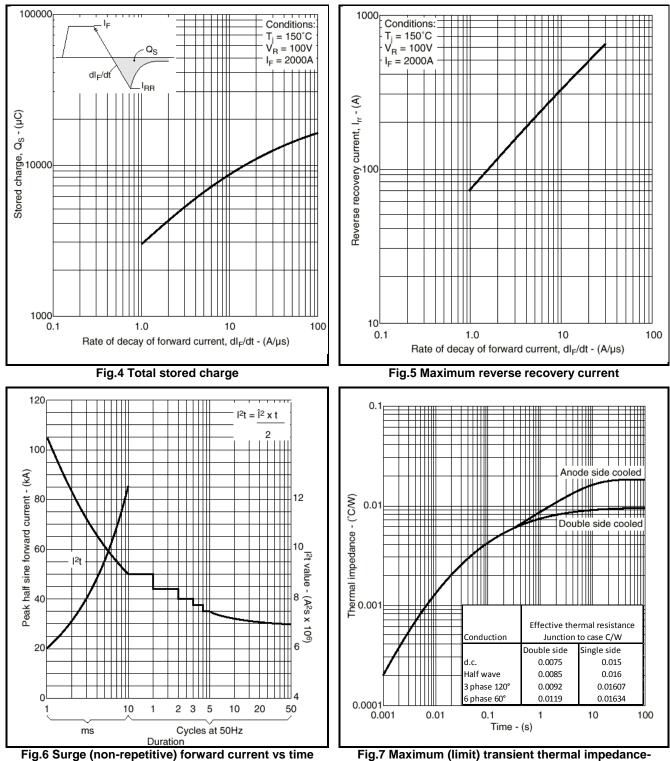


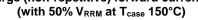
$V_{\mathsf{TM}} \text{ EQUATION}$

Where A = - 0.15357
B = 0.177571
C = 0.000179
D = - 0.01294
these values are valid for
$$T_j$$
 = 150°C for I_F 500A to 5000A

$$V_{TM} = A + BIn (I_T) + C.I_T + D.\sqrt{I_T}$$

DRD3390V40

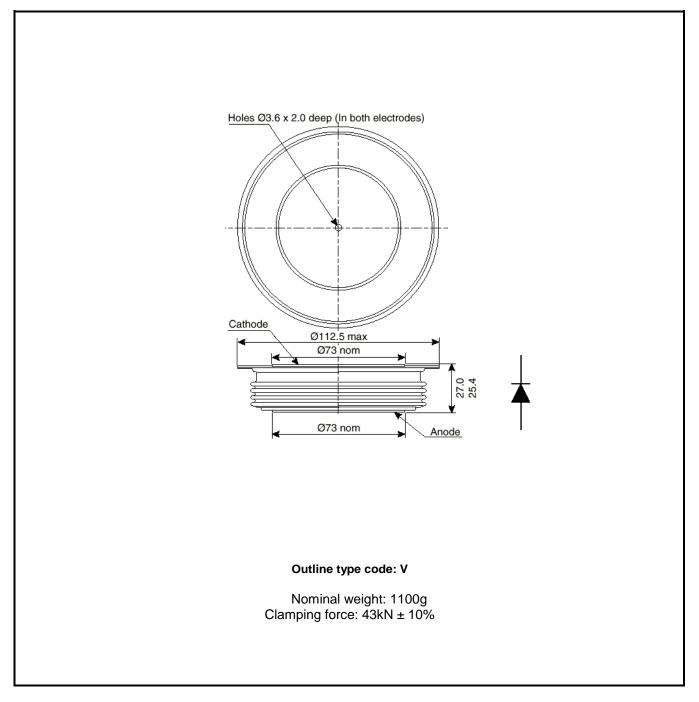




ig.7 Maximum (limit) transient thermal impedance junction to case

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.

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HEADQUARTERS OPERATIONS

DYNEX SEMICONDUCTOR LIMITED Doddington Road, Lincoln, Lincolnshire, LN6 3LF United Kingdom. Phone: +44 (0) 1522 500500 Web: http://www.dynexsemi.com

CUSTOMER SERVICE

Phone: +44 (0) 1522 502753 / 502901 e-mail: power_solutions@dynexsemi.com

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